

UNITED STATES PATENT AND TRADEMARK OFFICE



UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	O. FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO. 3425
10/046,259	10/046,259 01/10		Masatoshi Nakagawa	36856.606	
	7590	01/21/2004	EXAMINER		
Keating & B	ennett LI	LP .	KIM, PAUL D		
Suite 312					
10400 Eaton I	Place			ART UNIT	PAPER NUMBER
Fairfax, VA 22030				3729	_
				DATE MAILED: 01/21/2004	4

Please find below and/or attached an Office communication concerning this application or proceeding.

		<u>ب</u>	_
	Application No.	Applicant(s)	
•	10/046,259	NAKAGAWA ET AL.	
Office Action Summary	Examiner	Art Unit	
	Paul D Kim	3729	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPLY	Y IS SET TO EXPIRE 3 MONTH	H(S) FROM	
 THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). 	36(a). In no event, however, may a reply be y within the statutory minimum of thirty (30) d will apply and will expire SIX (6) MONTHS fro, cause the application to become ABANDON	timely filed ays will be considered timely. m the mailing date of this communication. IED (35 U.S.C. § 133).	
Status 1) Responsive to communication(s) filed on			
,	– action is non-final.		
Since this application is in condition for allowar closed in accordance with the practice under E	nce except for formal matters, p	rosecution as to the merits is 453 O.G. 213.	
Disposition of Claims			
4) Claim(s) 11-20 is/are pending in the application	n.		
4a) Of the above claim(s) is/are withdraw	wn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>11-13,16,19 and 20</u> is/are rejected.			
7)⊠ Claim(s) <u>14, 15, 17 and 18</u> is/are objected to.			
8) Claim(s) are subject to restriction and/or	r election requirement.		
Application Papers			
9)⊠ The specification is objected to by the Examine			
10) The drawing(s) filed on is/are: a) acce	•		
Applicant may not request that any objection to the			
Replacement drawing sheet(s) including the correct			
11) The oath or declaration is objected to by the Ex	aminer. Note the attached Οπίο	e Action of form P1O-152.	
Priority under 35 U.S.C. §§ 119 and 120			
a) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the prior application from the International Bureau * See the attached detailed Office action for a list of the since a specific reference was included in the first	s have been received. s have been received in Applica rity documents have been recei u (PCT Rule 17.2(a)). of the certified copies not receive c priority under 35 U.S.C. § 119	ation No. <u>09/654,114</u> . ved in this National Stage ved. ve(e) (to a provisional application)	
37 CFR 1.78. a) ☐ The translation of the foreign language pro			
14)⊠ Acknowledgment is made of a claim for domestic reference was included in the first sentence of the	c priority under 35 U.S.C. §§ 12	0 and/or 121 since a specific	
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 3	5) Notice of Informal	ry (PTO-413) Paper No(s) Patent Application (PTO-152)	

DETAILED ACTION

Specification

1. The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

The following title is suggested: --A METHOD FOR MANUFACTURING A SURFACE ACOUSTIC WAVE DEVICE--.

Claim Objections

2. Claims 17-19 are objected to because of the following informalities:

Re. Claim 17: The phrase "a portion of the thin metallic film" recited in lines 3-4 is not clear as to what the thin metallic film is indicated. Is it the first thin metallic film or second thin metallic film? Appropriate correction is required.

The phrase "a side" recited in line 4 should be -a side--.

Re. Claim 18: The phrase "the metallic thin film" recited in lines 1-2 is not clear as to what the thin metallic film is indicated. Is it the first thin metallic film or second thin metallic film?

Also, the phrase "the laminated thin film includes... component" recited in lines 3-6 is objected because when materials recited in a claim are so related as to constitute a proper **Markush group**, they may be recited in the conventional manner, or alternatively. For example, if "wherein R is a material selected from the group consisting

Application/Control Number: 10/046,259

Art Unit: 3729

of A, B, C and D" is a proper limitation, then "wherein R is A, B, C or D" shall also be considered proper (see MPEP 2173.05(h)).

Re. Claim 19: The phrase "the thickness" recited in lines 1-2 should be –a thickness--.

3. Claim 20 is objected to under 37 CFR 1.75(c), as being of improper dependent form for failing to further limit the subject matter of a previous claim. Applicant is required to cancel the claim(s), or amend the claim(s) to place the claim(s) in proper dependent form, or rewrite the claim(s) in independent form. There is no such a limitation such as "wherein the piezoelectric plate and the at least one interdigital electrode are arranged" recited in lines 1-2.

Claim Rejections - 35 USC § 112

- 4. The following is a quotation of the second paragraph of 35 U.S.C. 112:

 The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 5. Claim 20 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The phrase "wherein the piezoelectric plate and the at least one interdigital electrode are arranged" recited in lines 1-2 renders the claimed vague and indefinite. It is unclear as to where and how the piezoelectric plate and the at least one interdigital electrode are arranged.

Application/Control Number: 10/046,259 Page 4

Art Unit: 3729

Claim Rejections - 35 USC § 103

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 11, 12, 16, 19 and 20 are, as best understood in view of the rejections under 112 second paragraphs, rejected under 35 U.S.C. 103(a) as being unpatentable over Colgan et al. (US PAT. 5,281,485) in view of Fujimoto et al. (US PAT. 6,088,462).

Colgan et al. teach a process of making an electrical structure comprising steps of: providing a <u>substrate (SiO₂)</u>; forming a first metallic thin film (Ta (N)) on the substrate; and forming a second metallic thin film including a tantalum such as α-tantalum on the first metallic thin film as shown in Fig. 1B (see also col. 1, lines 19-24,col. 3, lines 18-56 and col. 5, line 44 to col. 6, line 48).

However, Colgan et al. do not teach a piezoelectric plate to form the first and second metallic thin films. Fujimoto et al. teach a process of making a surface acoustic wave device comprising steps of providing a substrate (2) made of piezoelectric and forming at least one metallic thin film such as tantalum on the substrate in order to provide superior stable temperature characteristics as shown in Fig. 1A (see also col. 1, lines 15-65 and col. 5, line 5 to col. 6, line 46). Therefore, it would also have been obvious at the time the invention was made to a person having ordinary skill in the art to modify the substrate of Colgan et al. by α-tantalum on the substrate as taught by Fujimoto et al. in order to provide superior stable temperature characteristics.

Application/Control Number: 10/046,259

Art Unit: 3729

As per claim 12 Colgan et al. teach that the metallic thin films are formed by sputtering disclosed in col. 5, line 44 to col. 6, line 48.

As per claim 16 Colgan et al. teach that the first metallic thin film includes a tantalum as shown in Fig. 1B.

As per claim 19 Colgan et al. teach that a thickness of the first metallic thin film is about 3.2 nm.

As best understood in view of the rejections under 112 second paragraphs for claim 20 Fujimoto et al. teach that interdigital electrode is formed on the piezoelectric substrate as shown in Fig. 1A.

8. Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over Colgan et al. in view of Fujimoto et al., and further in view of Kimura et al. (US PAT. 5,929,723).

Colgan et al., modified by Fujimoto et al., teach all of the limitations except vapor deposition to form the metallic thin films. Kimura et al. teach a process of making a surface acoustic wave device including a process of forming a thin metallic film such as tantalum on a substrate by vapor deposition in order to deposit the metallic layer evenly on the substrate (see also, col. 1, lines 32-39). Therefore, it would also have been obvious at the time the invention was made to a person having ordinary skill in the art to modify deposition process of Colgan et al., modified by Fujimoto et al., by vacuum deposition as taught by Kimura et al. in order to deposit the metallic layer evenly on the substrate.

9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Colgan et al. (US PAT. 5,221,449) and Arcidiacono et al. (US

Application/Control Number: 10/046,259

Art Unit: 3729

PAT. 4,410,867) are cited to further show the state of the art with respect to method of forming alpha tantalum.

Allowable Subject Matter

10. Claims 14 and 15 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

11. Claims 17 and 18 would be allowable if rewritten to overcome the objections, set forth in this Office action and to include all of the limitations of the base claim and any intervening claims.

Conclusion

12. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Paul D Kim whose telephone number is 703-308-8356. The examiner can normally be reached on Tuesday-Friday between 8:00 AM to 5:30 PM. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Peter Vo can be reached on 703-308-1789. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-306-5648.

Paul D Kim Examiner Art Unit 3729 Page 6